



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of )  
 Shunpei YAMAZAKI et al. )  
 Serial No. 09/239,948 ) Art Unit: 2814  
 Filed: January 29, 1999 ) Ex: G. Munson  
 For: LASER PROCESSING METHOD, )  
 METHOD FOR FORMING A FLASH )  
 MEMORY, INSULATED GATE )  
 SEMICONDUCTOR DEVICE AND )  
 METHOD FOR FORMING THE SAME )

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INFORMATION DISCLOSURE STATEMENT  
AND PETITION REQUESTING CONSIDERATION OF  
REFERENCES

Honorable Commissioner of Patents and Trademarks  
 Washington, D.C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, it is requested that the references listed on the attached Form PTO-1449 be made of record in the above-identified application.

A copy of the references are submitted herewith in accordance with 37 C.F.R. 1.98(a).

Each item of information in the attached Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this information disclosure statement, or (2) no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign patent application and no item of information contained in the

information disclosure statement was known to any individual designated in 37 C.F.R. § 1.56(c) more than three months prior to the filing of this information disclosure statement.

Submitted herewith is the requisite fee of \$180.00 and it is requested that this be treated as a petition for consideration of this Information Disclosure Statement. Hence, it is requested that the references submitted herewith be considered and made of record in the subject application.

Respectfully submitted,



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METHOD FOR FORMING THE )  
SAME )

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT


Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Supplemental to the Information Disclosure Statement filed December 12, 2000, attached please find a corrected PTO Form 1449 and two U.S. references which were inadvertently not attached to the IDS. It is respectfully requested that the reference(s) listed on the attached Form PTO-1449 be made of record in the above-identified application.

The Commissioner is hereby authorized to charge fees under 37 CFR 1.16 and 1.17 (except the Issue Fee) which may be required now or hereafter, or credit any overpayment, to Deposit Account No. 19-2380. A duplicate copy of this sheet is attached.

Respectfully submitted,

  
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